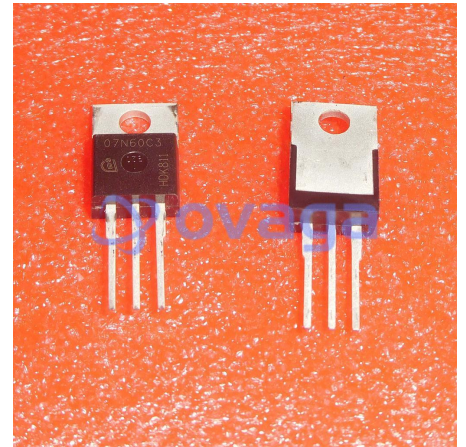


N-Channel MOSFETs (>500V...900V); Package: PG-TO220-3; VDS (max): 600.0 V;
 Package: TO-220; RDS(ON) @ TJ=25°C VGS=10: 600.0 mOhm; ID(max) @ TC=25°C:
 7.3 A; IDpuls (max): 21.9 A; MOSFET COOL MOS N-CH 650V 7.3A

Manufacturers	<u>Infineon Technologies Corporation</u>
Package/Case	TO-220AB
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for SPP07N60C3 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

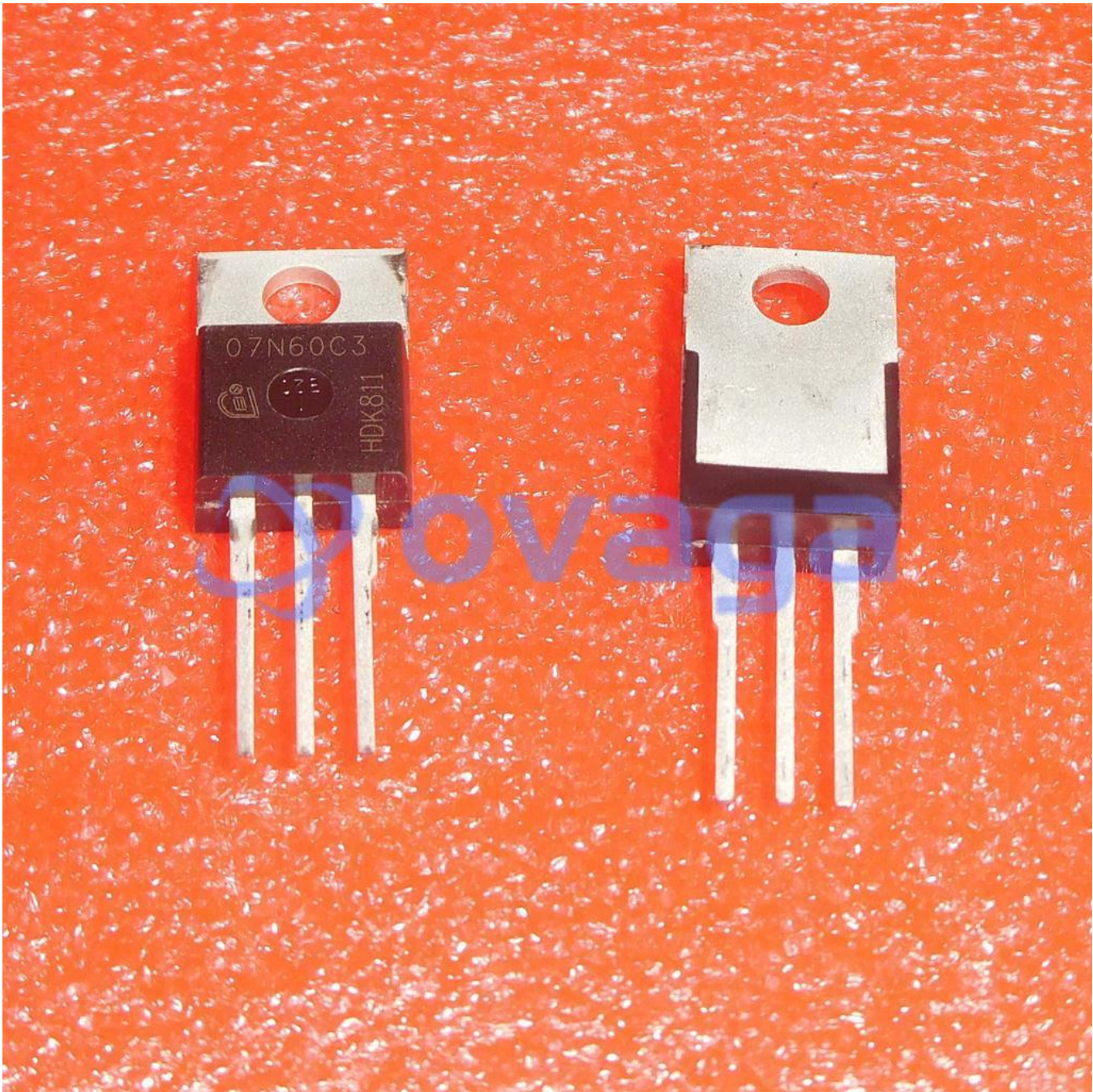
SPP07N60C3 is a type of power MOSFET, which is a semiconductor device used for switching and amplifying electronic signals. Specifically, SPP07N60C3 is a 600V, 7A N-channel MOSFET manufactured by Infineon Technologies.

Features

- Low on-resistance
- Fast switching speed
- High ruggedness
- Avalanche energy rated
- Low gate charge

Application

- Switching power supplies
- Motor control circuits
- Lighting systems
- Audio amplifiers
- DC-DC converters
- Uninterruptible power supplies (UPS)
- Solar inverters



Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



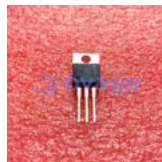
[SPP11N65C3](#)

Infineon Technologies Corporation
TO-220



[SPP07N65C3](#)

Infineon Technologies Corporation
TO-220AB



[SPP07N60S5](#)

Infineon Technologies Corporation
P-TO220-3-1



[SPP11N60C3XKSA1](#)

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PG-TO220



[IRF640NSPBF](#)

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PAK-3



[SPD03N60S5](#)

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[SPP20N60CFD](#)

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TO-220AB